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CORRECTION

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Correction: Nanoparticles of Cu₂ZnSnS₄ as performance enhancing additives for organic field-effect transistors

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Correction for 'Nanoparticles of Cu_2ZnSnS_4 as performance enhancing additives for organic field-effect transistors' by Punarja Kevin et al., J. Mater. Chem. C, 2016, DOI: 10.1039/c6tc01650b.

On the third page of this article there in an additional, erroneous value included in the list of d-spacings and 69.34 should not appear. The correct sentence is as follows: "The p-XRD pattern (Fig. 1) of the sample prepared at 220 °C for 1 hour shows main peaks at d-spacings of: 3.14, 2.73, 1.92, 1.64, 1.35 and 1.24 for the (112), (200), (204), (312), (400) and (316) spacings of kesterite CZTS (ICDD: 04-015-0223)."

The Royal Society of Chemistry apologises for these errors and any consequent inconvenience to authors and readers.

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